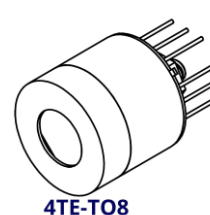


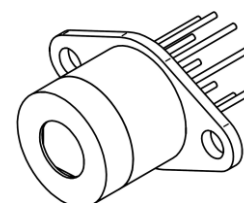
PC-10.6 DETECTOR SERIES

DATASHEET

HgCdTe thermoelectrically cooled photoconductive infrared detectors



4TE-TO8



4TE-TO66

FEATURES

- Spectral range: over 13.0 μm
- Front-side illuminated
- No minimum order quantity required

RELATED PRODUCTS

- [LabM-I-10.6 detection module](#)
- [UM-I-10.6 detection module](#)
- [microM-10.6 detection module](#)
- [PVIA-10.6-1x1-TO39-NW-36 RoHS-compliant detector](#)
- [PVIA-4TE-10.6-1x1-TO8-wZnSeAR-36 RoHS-compliant detector](#)

APPLICATIONS

- Gas detection, monitoring and analysis: SO_2 , NH_3 , SF_6
- CBRN threats detection
- CO_2 laser measurements: power monitoring and control, beam profiling and positioning, calibration
- Free-space optical communication
- FTIR spectroscopy
- Bacteria identification in medicine
- Dentistry
- Glucose sensing

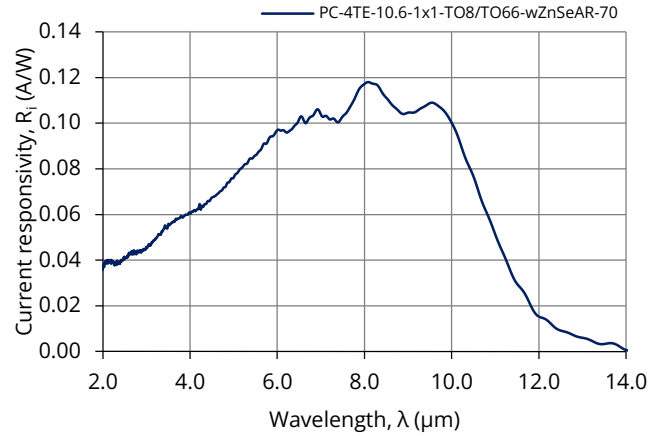
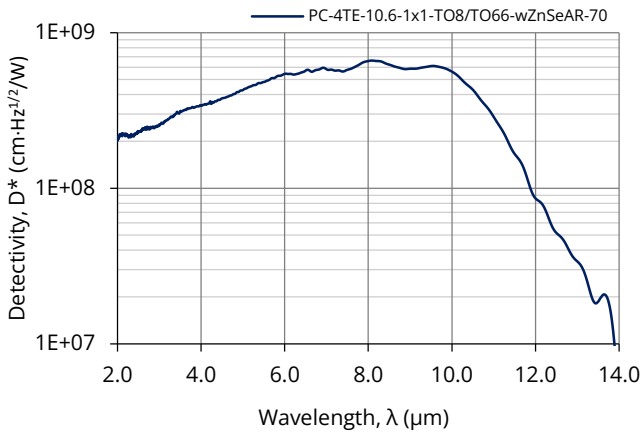
SERIES DESCRIPTION

Detector symbol	Cooling	Temperature sensor	Active area, A, mm \times mm	Optical immersion	Package	Acceptance angle, Φ , deg.	Window
PC-4TE-10.6-1x1-TO8-wZnSeAR-70	4TE	thermistor	1 \times 1	no	4TE-TO8	~70	wZnSeAR (3 deg. zinc selenide, anti-reflection coating)
PC-4TE-10.6-1x1-TO66-wZnSeAR-70	$T_{\text{chip}} \cong 200\text{K}$				4TE-TO66		

SPECIFICATION ($T_{\text{amb}} = 293 \text{ K}$, $V_b = 0.4 \text{ V}$)

Detector symbol	Peak wavelength			Specific wavelength			Cut-off wavelength (10%)			Detectivity		Current responsivity			Time constant	Resistance	Bias voltage	1/f corner frequency
	λ_{peak}	λ_{spec}	$\lambda_{\text{cut-off}}$	$D^*(\lambda_{\text{peak}}, 20\text{kHz})$	$D^*(\lambda_{\text{spec}}, 20\text{kHz})$	$R(\lambda_{\text{peak}})$	$R(\lambda_{\text{spec}})$	τ	R	V_b	f_c							
	μm	μm	μm	$\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$	$\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$	A/W	A/W	ns	Ω	V	kHz							
	Typ.	Typ.	Typ.	Typ.	Min.	Typ.	Typ.	Min.	Typ.	Typ.	Max.	Typ.	Typ.					
PC-4TE-10.6-1x1-TO8-wZnSeAR-70	8.5 \pm 0.6	10.6	13.0	6.5 \times 10 ⁸	3.5 \times 10 ⁸	4.0 \times 10 ⁸	0.06	0.03	0.06	30	250	0.4	20					
PC-4TE-10.6-1x1-TO66-wZnSeAR-70																		

SPECTRAL RESPONSE (Typ., $T_{amb} = 293\text{ K}$)



MECHANICAL LAYOUT AND PINOUT

- [4TE-TO8\(12p\)-wW, PC detector technical drawing](#)
- [4TE-TO66\(9p\)-wW, PC detector technical drawing](#)

RECOMMENDED AMPLIFIERS

Detector symbol	Amplifier type
PC-4TE-10.6-1x1-TO8-wZnSeAR-70	AIP series
	PIP series
	MIP series
	SIP-TO8 series

ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions, remarks	Value	Unit
Ambient operating temperature, T_{amb}	Operation at $T_{amb} > 30^{\circ}\text{C}$ may increase the active element temperature and reduce the performance of the detector below specified parameters	-20 to 30	$^{\circ}\text{C}$
Storage temperature, T_{stg}		-20 to 50	$^{\circ}\text{C}$
Soldering temperature	Within 5 s or less	≤ 300	$^{\circ}\text{C}$
Storage humidity	No dew condensation	10 to 90	%
Maximum incident optical power density	Continuous wave (CW) or single pulses $> 1\ \mu\text{s}$ duration	100	W/cm^2
	Single pulses $< 1\ \mu\text{s}$ duration	1	MW/cm^2
Maximum bias voltage, $V_{b,max}$		2.0	V
Maximum TEC voltage, $V_{TEC,max}$	4TE	8.3	V
Maximum TEC current, $I_{TEC,max}$	4TE	0.4	A

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device.